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Stocking Distributor

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Diodes Incorporated ZXTN10150DZTA

For any questions, you can email us directly: <u>sales@integrated-circuit.com</u>







A Product Line of Diodes Incorporated



ΙX

150V NPN LED DRIVING TRANSISTOR IN SOT89

Features

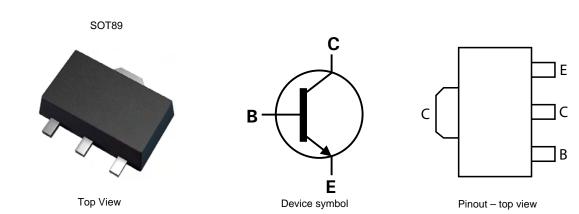
- BV_{CEO} > 150V
- $h_{FE} > 100$ for $I_C = 150mA$, $V_{CE} = 0.25V$
- I_{C (cont)} = 1A
- Lead Free, RoHS Compliant (Note 1)
- Halogen and Antimony Free "Green" Device (Note 2)
- Qualified to AEC-Q101 Standards for High Reliability

Applications

LED TV backlight

Mechanical Data

- Case: SOT-89
- Case Material: Molded Plastic. "Green" Molding Compound.
- UL Flammability Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminals: Matte Tin Finish
- Weight: 0.008 grams (Approximate)



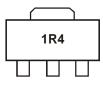
Ordering Information

Product	Marking	Reel size (inches)	Tape width (mm)	Quantity per reel
ZXTN10150DZTA	1R4	7	12	1000

Notes: 1. No purposefully added lead.

2. "Green" devices, Halogen and Antimony Free, Diodes Inc's "Green" Policy can be found on our website at http://www.diodes.com

Marking Information



1R4 - Product Type Marking Code







ZXTN10150DZ

Maximum Ratings @T_A = 25°C unless otherwise specified

Characteristic	Symbol	Value	Unit
Collector-Base Voltage	V _{CBO}	150	V
Collector-Emitter Voltage	V _{CEO}	150	V
Emitter-Base Voltage	V _{EBO}	7	V
Continuous Collector Current	lc	1	A
Peak Pulse Current (Note 4)	I _{CM}	3	A
Base Current	IB	500	mA

Thermal Characteristics @T_A = 25°C unless otherwise specified

Characteristic	Symbol	Value	Unit
Characteristic	Symbol	Value	Unit
Power Dissipation (Note 3)	PD	1.5	W
Thermal Resistance, Junction to Ambient (Note 3)	R _{θJA}	83	°C/W
Thermal Resistance, Junction to Leads	R _{θJL}	6.36	°C/W
Operating and Storage Temperature Range	T _{J,} T _{STG}	-55 to +150	°C

3. For a device surface mounted on 25mm X 25mm FR4 PCB with high coverage of single sided 1 oz copper, in still air conditions. Notes: 4. Measured under pulsed conditions. Pulse width = 300μ s. Duty cycle $\leq 2\%$.



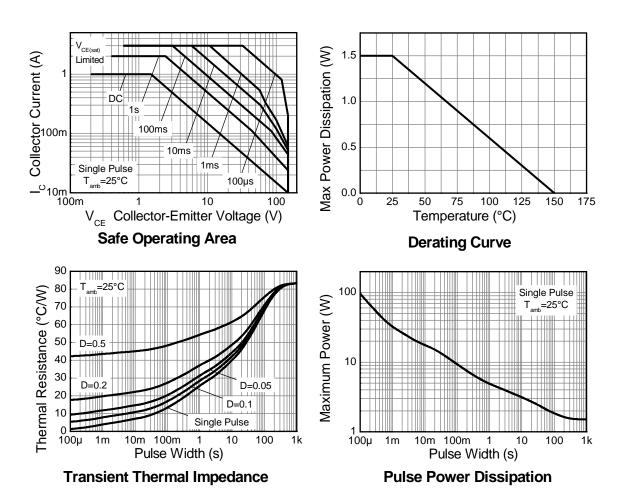


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Thermal Characteristics and Derating information







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Electrical Characteristics @T _A = 25	5°C unless otherwise	specified				
Characteristic	Symbol	Min	Тур	Max	Unit	Test Condition
Collector-Base Breakdown Voltage	BV _{CBO}	150	300	-	V	I _C = 100μA
Collector-Emitter Breakdown Voltage (Note 5)	BV _{CEO}	150	175	-	V	$I_{\rm C} = 10 {\rm mA}$
Emitter-Base Breakdown Voltage	BV _{EBO}	7	8.3	-	V	I _E = 100μA
Collector Cut-off Current	I _{CBO}	-	-	50	nA	V _{CB} = 150V
Emitter Cut-off Current	I _{EBO}	-	-	50	nA	$V_{EB} = 7V$
Static Forward Current Transfer Ratio (Note 5)	hFE	200 60 100	450 180 150		-	$I_{C} = 30$ mA, $V_{CE} = 5V$ $I_{C} = 85$ mA, $V_{CE} = 0.20V$ $I_{C} = 150$ mA, $V_{CE} = 0.25V$
Base-Emitter Turn-On Voltage (Note 5)	V _{BE(on)}	-	0.701	0.95	V	I _C = 150mA, V _{CE} = 0.25V
Output Capacitance	C _{OBO}	-	10	-	pF	V _{CB} = 10V, f = 1MHz
Current Gain-Bandwidth Product	ft	-	135	-	MHz	$V_{CB} = 10V$, Ic = 10mA, f = 100MHz
Delay Time	t _(d)	-	625	-	ns	
Rise Time	t _(r)	-	562	-	ns	V _{CC} = 110V, I _C = 150mA,
Storage Time	t _(s)	-	2465	-	ns	-I _{B2} = 1.5mA, V _{CE} (_{ON}) = 0.25V
Fall Time	t _(f)	-	289	-	ns	
Storage Time	t _(s)	-	461	-	ns	V _{CC} = 110V, I _C = 150mA,
Fall Time	t _(f)	-	52	-	ns	$-I_{B2} = 1.5 \text{mA}, V_{CE(ON)} = 4 \text{V}$

Notes: 5. Measured under pulsed conditions. Pulse width = 300μ s. Duty cycle $\leq 2\%$



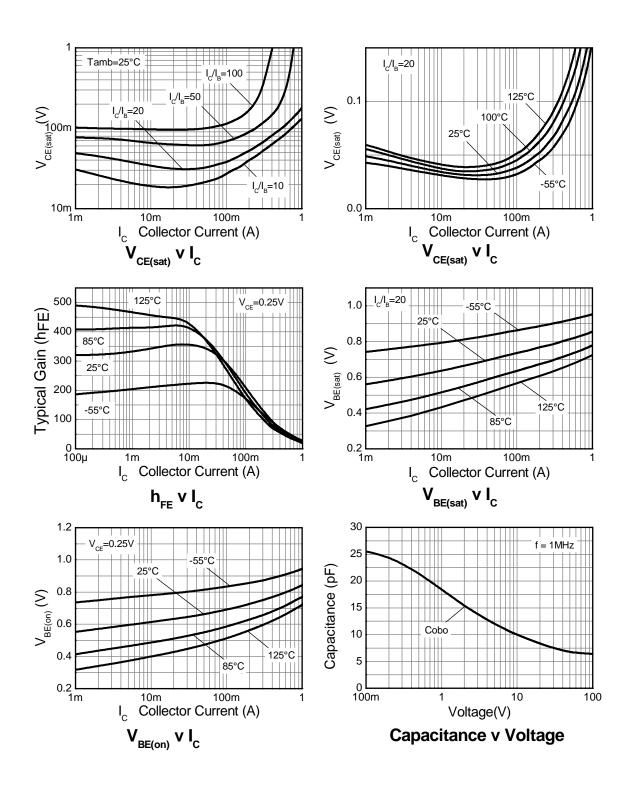


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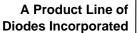
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Typical Characteristics





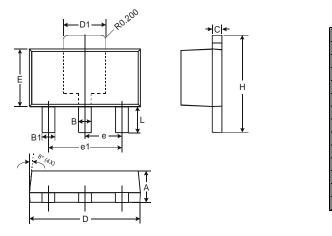






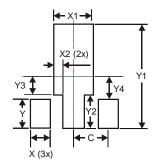
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Package Outline Dimensions



SOT89-3L				
Dim	Min	Max		
Α	1.40	1.60		
В	0.44	0.62		
B1	0.35	0.54		
С	0.35	0.43		
D	4.40	4.60		
D1	1.52	1.83		
Е	2.29	2.60		
е	1.50 Typ			
e1	3.00 Typ			
Н	3.94	4.25		
L	0.89	1.20		
All Dimensions in mm				

Suggested Pad Layout



Dimensions	Value (in mm)			
Х	0.900			
X1	1.733			
X2	0.416			
Y	1.300			
Y1	4.600			
Y2	1.475			
Y3	0.950			
Y4	1.125			
С	1.500			







ZXTN10150DZ

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